

L Number	Hits	Search Text	DB	Time stamp
1	68493	Ion adj implantation	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/09/15 10:08
2	5	((Ion adj implantation) and (cut near4 error)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/09/15 10:17
3	341	((Ion adj implantation) and (crystal near4 cut)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/09/15 10:18
4	0	((Ion adj implantation) and (crystal near4 cut)) and (cut near4 error)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/09/15 10:18
5	1	((Ion adj implantation) and (crystal near4 cut)) and (crystal near4 error)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/09/15 10:27
6	118	((Ion adj implantation) and (crystal near4 cut)) and (crystal near4 orientation)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/09/15 10:27
7	0	((Ion adj implantation) and (crystal near4 cut)) and (crystal near4 orientation)) and (shadowing near4 wafer)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/09/15 11:09
9	79	((Ion adj implantation) and (channeling near4 wafer)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/09/15 11:10
10	3	((Ion adj implantation) and (channeling near4 wafer)) and (shadowing near4 wafer)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/09/15 11:16
11	3240	((250/492.21,) or (414/935,) or (428/64.1,) or (257/797,)).CCLS.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/09/15 11:17
12	9	((250/492.21,) or (414/935,) or (428/64.1,) or (257/797,)).CCLS.) and (crystal near4 cut)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/09/15 14:11
8	20	((Ion adj implantation) and (shadowing near4 wafer)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/09/15 11:25
13	4	((250/492.21,) or (414/935,) or (428/64.1,) or (257/797,)).CCLS.) and (shadowing near4 wafer)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/09/15 11:26
14	0	((250/492.21,) or (414/935,) or (428/64.1,) or (257/797,)).CCLS.) and (cut near4 error)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/09/15 11:26

15	2	((250/492.21,) or (414/935,) or (428/64.1,) or (257/797,)).CCLS.) and (crystal near4 error)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/09/15 11:36
16	5	6,255,662	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/09/15 11:41
17	21	4,975,586	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/09/15 11:41
18	563	((250/492.21,) or (414/935,) or (428/64.1,) or (257/797,)).CCLS.) and (ion near4 implantation)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/09/15 14:12
19	2	((250/492.21,) or (414/935,) or (428/64.1,) or (257/797,)).CCLS.) and (ion near4 implantation) and (crystal near4 error)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/09/15 14:13

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